NSN 5961-01-375-0801

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Internal Configuration:
Junction contact
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
20.0 collector to base voltage/static/emitter open and 10.0 collector to emitter voltage/static/base open and 1.5 emitter to base voltage
static, collector open
Current Rating Per Characteristic:
65.00 milliamperes all primaries
Power Rating Per Characteristic:
290.0 watts any acceptable preset
Transfer Ratio:
250.0 static forward current transfer ratio, common-emitter
Maximum Operating Tempurature Per Measurement Point:
200.0 degrees celsius junction
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
No
Fiig:
A110a0